

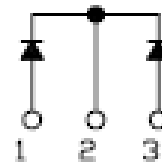
## SDURF2060CTA ULTRAFAST PLASTIC RECTIFIER

### Applications:

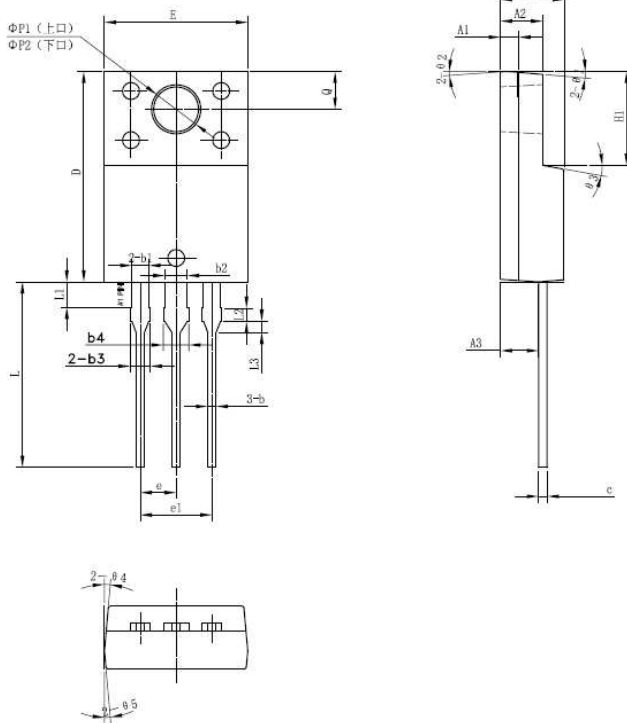
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

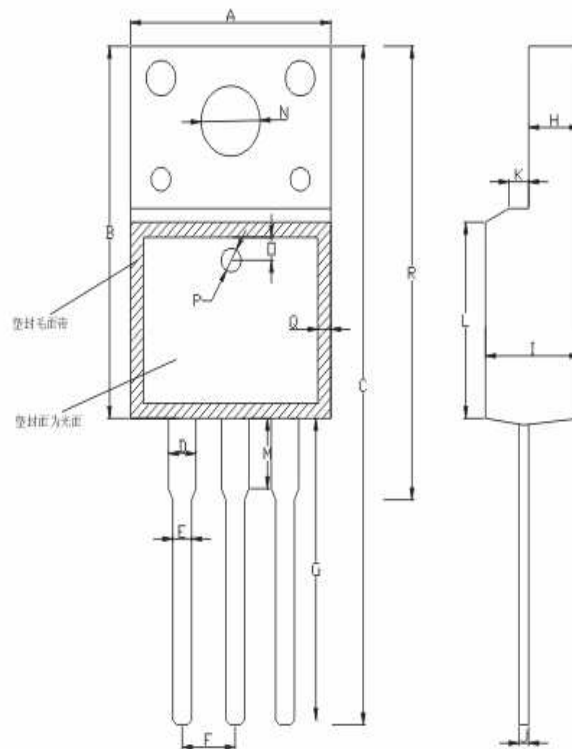


### Mechanical Dimensions: In mm



SYMBOL	MIN.	TYP.	MAX.
A	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	0.60	0.75
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
c	0.55	0.60	0.75
D	14.80	15.00	15.20
E	9.96	10.16	10.36
e		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L3	0.60	0.80	1.00
ΦP1(上孔)	3.30	3.50	3.70
ΦP2(下孔)	2.99	3.19	3.39
Q	2.50	2.70	2.90
Θ1		5°	
Θ2		4°	
Θ3		10°	
Θ4		5°	
Θ5		5°	

### OPTION 1(HD)



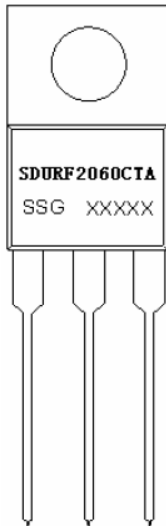
A:10.20 ± 0.50	B:15.90 ± 0.50	C:29.00 ± 1.00	D:1.24 ± 0.10
E:0.80 ± 0.10	F:2.54 ± 0.10	G:13.10 ± 1,0	H:2.55 ± 0.05
I:4.70 ± 0.05	J:0.50 ± 0.05	K:1.20 ± 0.20	L:8.00 ± 0.50
M:3.00 ± 0.50	N:3.20 ± 0.20	O:1,25 ± 0.05	P:1.5 ± 0.05
Q:1.0 ± 0.20	R:19.2 ± 1.0		

**OPTION 2(SR)**

**ITO-220AB**

Technical Data  
Data Sheet N0437, Rev. A

**Marking Diagram:**



Where XXXXX is YYWWL

SDUR = Device Type  
F = Package type  
20 = Forward Current (20A)  
60 = Reverse Voltage (600V)  
CTA = Configuration  
SSG = SSG  
YY = Year  
WW = Week  
L = Lot Number

**Cautions:** Molding resin  
Epoxy resin UL:94V-0

**Ordering Information:**

Device	Package	Shipping
SDURF2060CTA	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	600	V
Average Forward Current	$I_{F(AV)}$	50% duty cycle @Tc=100°C, rectangular wave form	20	A
Peak One Cycle Non-Repetitive Surge Current (Per leg)	$I_{FSM}$	8.3ms, Half Sine pulse	100	A



**Electrical Characteristics:**

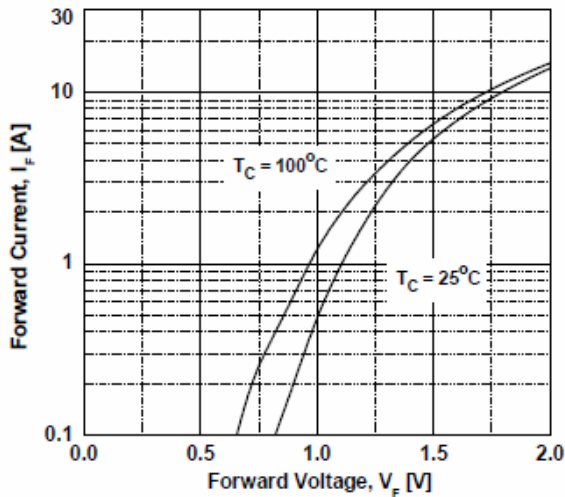
Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@10A, Pulse, $T_J = 25^\circ\text{C}$	2.2	V
	$V_{F2}$	@10A, Pulse, $T_J = 125^\circ\text{C}$	2.0	V
Reverse Current*	$I_{R1}$	@ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$	10	$\mu\text{A}$
	$I_{R2}$	@ $V_R = V_R$ $T_J = 125^\circ\text{C}$	500	$\mu\text{A}$
Reverse Recovery Time	$t_{rr}$	$I_F=500\text{mA}$ , $I_R=1\text{A}$ , and $I_{rm}=250\text{mA}$	35	ns

\* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

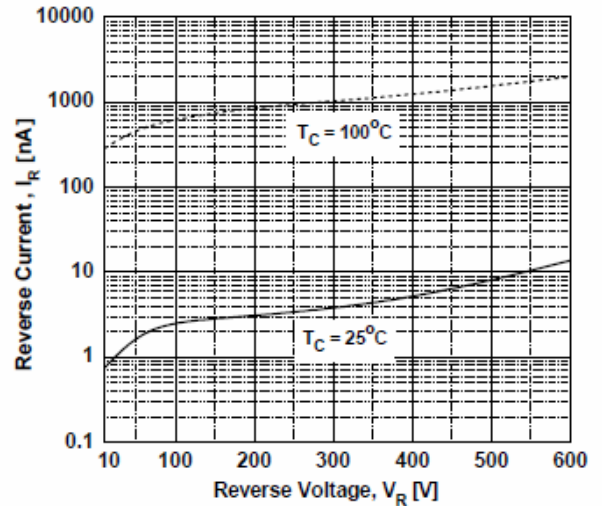
**Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-	-55 to +150	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	5.0	$^\circ\text{C/W}$
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

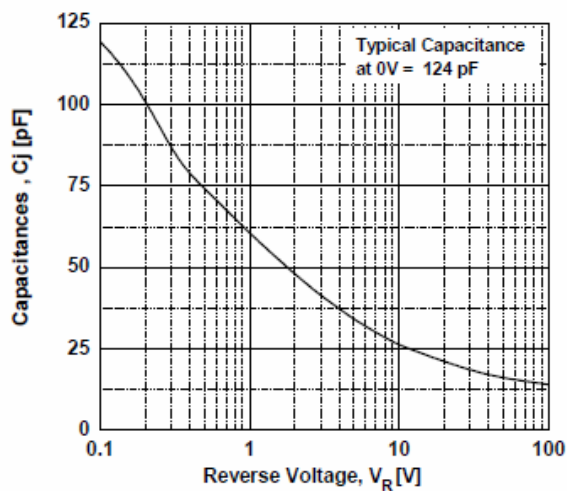
**Figure 1. Typical Forward Voltage Drop vs. Forward Current**



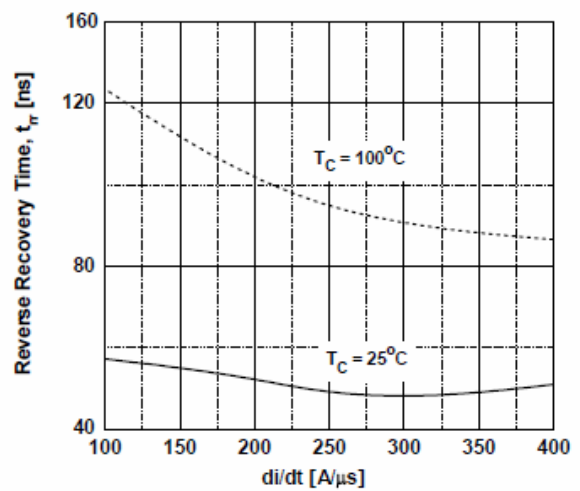
**Figure 2. Typical Reverse Current vs. Reverse Voltage**



**Figure 3. Typical Junction Capacitance**



**Figure 4. Typical Reverse Recovery Time vs. di/dt**



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